## (I) aic

## **1.0A Synchronous Step-Up Converter**

## **FEATURES**

- VIN Start Up Voltage: 0.9V
- Output Voltage Range: from 2.5V to 5.5V.
- Up to 94% Efficiency
- Up to 1.0A Continuous Output Current
- Allow EN pin Floating
- Built-in current mode compensation
- Built-in Protection: Over Current, Over Voltage, Over Temperature
- Optional Active High/Low EN pin
- Logic Controlled Shutdown: < 1µA</li>
- Output Disconnect by Shutdown Function
- Built-in Soft Start

## APPLICATIONS

- Li-Ion Type Battery Operated Products
- Power Bank
- Handheld Devices
- Portable Products

## **TYPICAL APPLICATION CIRCUITS**

### <sup>o</sup> 5Vout COUT2 COUT1 R3 U1 :22µF :22µF 3.6V<sub>IN</sub> L1 <100ΚΩ Ξ 9 2 VOUT R5 Х R4 3.3µH R6 6 1MΩ 3 KR1 VIN FB 11.1kO 100kO 7 100kΩ CIN 4 LBI LBO <sup>o</sup> LBO 10µF R2 10 8 PGND PGOOD <sup>o</sup> PGOOD 20kΩ 1 5 ΕN GND Chip Enable AIC3417

Typical Application Circuit for DFN-10 (3x3x0.75-0.5) Package

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## DESCRIPTION

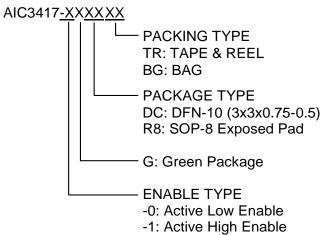
The AIC3417 is a high efficiency, step-up DC/DC converter with high light load efficiency. The true output disconnect function eliminates inrush current and allows Vout to go to zero during shutdown.

The AIC3417 is suited for high current boost application such as battery backup supplies or wireless devices powered by one Li-Ion battery or two Alkaline, Ni-Cd, Ni-MH battery.

The device includes a  $50m\Omega$  N-Ch MOSFET switch and a  $60m\Omega$  P-Ch MOSFET switch; it can provide high efficiency at 1.0A continuous output current. High efficiency is achieved at light load when PSM Mode operation is entered, where the IC's quiescent current is lower than  $20\mu$ A on Vout.

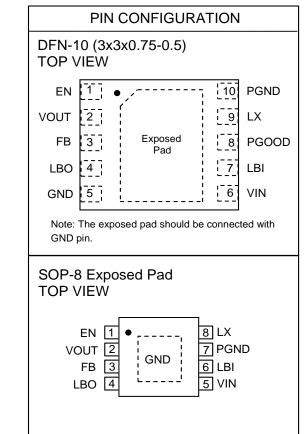
The AIC3417 is available in the DFN-10 (3x3x0.75-0.5) and SOP-8 Exposed Pad package.





Example: AIC3417-1GDCTR

 → Active High Enable, in DFN-10 (3x3x0.75-0.5) Package and Tape & Reel Packing Type





## ABSOLUTE MAXIMUM RATINGS

Supply Input Voltage, VIN		-0.3 V to 6V
Output Voltage, VOUT		-0.3 V to 6V
Switch Output Voltage, LX		
Digital Input Voltage, EN, LBI	-0.3 V to 6V	
Digital Output Voltage, LBO, PGOOD		
Other Pin		-0.3 V to 6V
Operating Ambient Temperature Range TA		
Operating Maximum Junction Temperature	150°C	
Storage Temperature Range T <sub>STG</sub>		-65°C to 125°C
Lead Temperature (Soldering 10 Sec.)		260°C
Thermal Resistance Junction to Case	SOP-8 Exposed Pad*	15°C/W
Thermal Resistance Junction to Case	DFN-10 (3x3x0.75-0.5)	20°C/W
Thermal Resistance Junction to Ambient	SOP-8 Exposed Pad*	60°C/W
Thermal Resistance Junction to Ambient	DFN-10 (3x3x0.75-0.5)	50°C/W
(Assume no ambient airflow, no heatsink)		

Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

\*The package is place on a two layers PCB with 2 ounces copper and 2 square inch, connected by 8 vias.



### **ELECTRICAL CHARACTERISTICS**

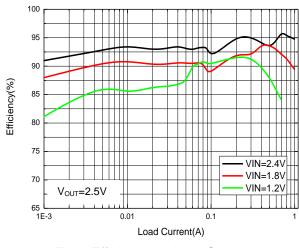
### (Typical application circuit, T<sub>A</sub>=25°C, V<sub>IN</sub>=3.6V, V<sub>OUT</sub>=5V, Unless otherwise specified) (Note1)

PARAMETER	<b>TEST CONDITION</b>	SYMBOL	MIN	ТҮР	MAX	UNIT
Output Voltage Range	I <sub>OUT</sub> =0A	V <sub>OUT</sub>	2.5		5.5	V
Minimum Start Up Voltage	I <sub>OUT</sub> =0A			0.9		V
Quiescent Current (Non-Switching)		I <sub>Q0</sub>		20	30	μA
Shut Down Current (Oscillator no switching)	Active High, EN= 0V, V <sub>IN</sub> =1.1V	I <sub>SD</sub>		0.3	1	μA
	Active Low, EN= $V_{IN}$ , $V_{IN}$ =1.1V	I <sub>SD</sub>		0.3	1	μA
Feedback Voltage	I <sub>OUT</sub> =0	V <sub>FB</sub>	0.49	0.5	0.51	V
FB Input Leakage Current		I <sub>FB</sub>		1	50	nA
Maximum Duty Cycle			80	88		%
Minimum Duty Cycle					0	%
NMOS Switch Leakage	V <sub>SW</sub> =5V			0.1	5	μA
PMOS Switch Leakage	V <sub>SW</sub> =5V			0.1	10	μA
NMOS Switch On Resistance				50		mΩ
PMOS Switch On Resistance				60		mΩ
EN High Threshold Voltage			1.2			V
EN Low Threshold Voltage					0.25	V
EN Input Current	EN= 5.25V	I <sub>EN</sub>		10		μA
NMOS Current Limit Setting			2.1	2.7	3.4	А
Power Good threshold voltage	Rising referred to $V_{\text{FB}}$		91	95	99	%
Power Good Hysteresis				5		%
Power Good Delay				10		μS
LBI Voltage Threshold	LBI falling		0.485	0.5	0.515	V
LBI Voltage Hysteresis				10		mV
LBO Output Impedance				150		Ω
Over Temperature Protection				150		°C
Over Temperature Hysteresis				25		°C

Note 1: Specifications are production tested at T<sub>A</sub>=25°C. Specifications over the -40°C to 85°C operating temperature range are assured by design, characterization and correlation with Statistical Quality Controls (SQC).

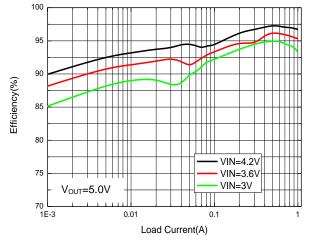
Note 2: Once the output is started, the IC is not dependant upon the VIN supply.

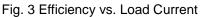
## **TYPICAL PERFORMANCE CHARACTERISTICS**



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Fig. 1 Efficiency vs. Load Current





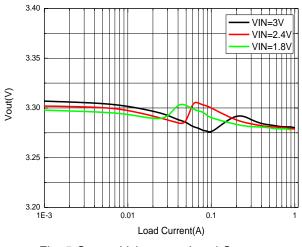


Fig. 5 Output Voltage vs. Load Current

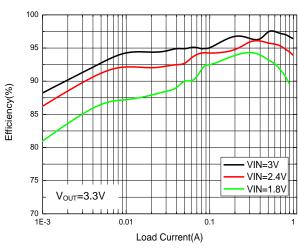
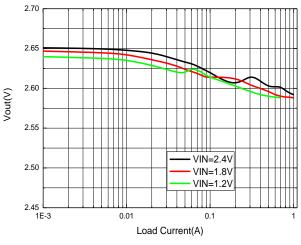
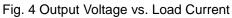


Fig. 2 Efficiency vs. Load Current





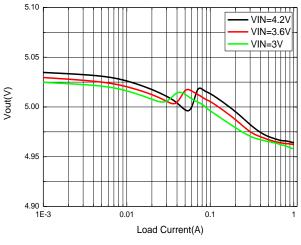
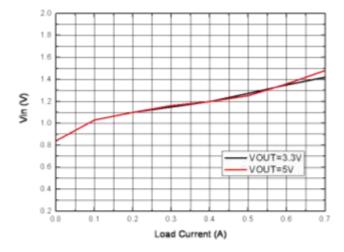


Fig. 6 Output Voltage vs. Load Current

## **TYPICAL PERFORMANCE CHARACTERISTICS (Continued)**



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Fig. 7 Start-up Voltage vs. Load Current

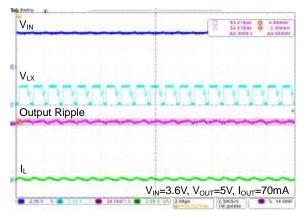


Fig. 9 Switching Waveform at DCM

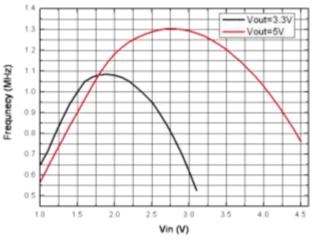


Fig. 11 Switching Frequency vs. Input Voltage

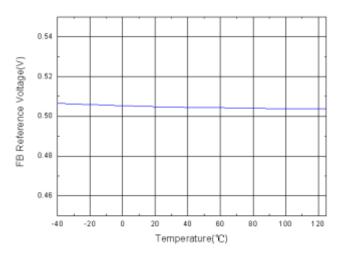


Fig. 8 Reference Voltage vs. Temperature

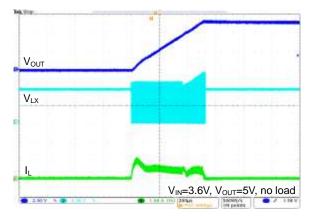
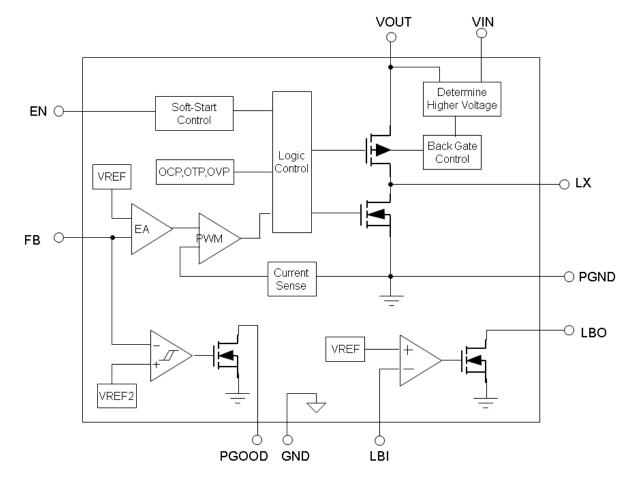


Fig. 10 Start-up Waveform





Functional Block Diagram of AIC3417



## **PIN DESCRIPTIONS**

## (For DFN-10 (3x3x0.75-0.5) PACKAGE)

Pin Number	Pin Name	Pin Function
1		Logic Controlled Shutdown Input.
	EN	There are two versions:
		Active High Version:
		EN = High: Normal Operation
		EN = Low or Floating: IC shutdown
		Active Low Version:
		EN = High or Floating: IC shutdown
		EN = Low: Normal Operation
2	VOUT	Output Voltage Sense and Drain of the Internal Synchronous Rectifier.
3	FB	Feedback Pin. This pin receives the feedback voltage from a resistive divider connect across the output.
4	LBO	Low-Battery Detector Output.
5	GND	Signal Ground.
6	VIN	Input Supply.
7	LBI	Low-Battery Detector Input.
8	PGOOD	Power Good Indicator.
9	LX	Switch Pin. Connect Inductor between VIN and this pin.
10	PGND	Power Ground.



## PIN DESCRIPTIONS (Continued)

## (For SOP-8 Exposed Pad PACKAGE)

Pin Number	Pin Name	Pin Function
1	EN	Logic Controlled Shutdown Input.
		There are two versions:
		Active High Version:
		EN = High: Normal Operation
		EN = Low or Floating: IC shutdown
		Active Low Version:
		EN = High or Floating: IC shutdown
		EN = Low: Normal Operation
2	VOUT	Output Voltage Sense and Drain of the Internal Synchronous Rectifier.
3	FB	Feedback Pin. This pin receives the feedback voltage from a resistive divider connect across the output.
4	LBO	Low-Battery Detector Output.
5	VIN	Input Supply.
6	LBI	Low-Battery Detector Input.
7	PGND	Power Ground.
8	LX	Switch Pin. Connect Inductor between VIN and this pin.
9 (Exposed Pad)	GND	Signal Ground.

# Application information

The AIC3417 is a synchronous step-up DC-DC converter. It is based on constant Off Time/PSM controller topology. At the beginning of each clock cycle, the main switch (NMOS) is turned on and the inductor current starts to ramp. After the sense current signal equals the error amplifier (EA) output, the main switch is turned off and the synchronous switch (PMOS) is turned on. The device can operate with an input voltage below 2.5V; the typical start-up voltage is 0.9V.

### **Current Limit Protection**

The over current protection can limit the main switch current. The output voltage will be dropped when over current is happened. The over current protection circuit will turn off the main switch once the current exceeds its threshold.

### **Zero Current Detection**

The zero current comparator monitors the inductor current to the output and shuts off the synchronous rectifier when the inductor current reduces to zero. This prevents the inductor current from reversing in polarity and improves the efficiency at light load condition.

### **Device Shutdown**

For the active high version, when EN is set logic high or floating, the AIC3417 is put into active mode operation. If EN is set logic low, the device is put into shutdown mode and consumes less than 1 $\mu$ A. At the shutdown mode, the synchronous switch will turn off and the output voltage of AIC3417 step-up converter will reduce to 0V. After start-up, the internal circuitry is supplied by VOUT. However, if shutdown mode is enabled, the internal circuitry will be supplied by the input source again.

### **Low-Battery Detection**

AIC3417 contains an on-chip comparator with 10mV internal hysteresis for low battery detection. If the voltage at LBI falls below 0.5V, LBO (an open-drain output) sinks current to GND. The component value of

resistor R5 connecting between LBO pin and VOUT pin should be larger than  $1M\Omega$ .

### **Power Good Indicator**

AIC3417 contains an on-chip comparator for power good detection. If the output voltage is lower than power good low threshold, PGOOD (an open-drain output) sinks current to GND.

### Adjustable Output Voltage

An external resistor divider is used to set the output voltage. The output voltage of the switching regulator  $(V_{OUT})$  is determined by the following equation:

$$V_{OUT} = V_{FB} \times \left(1 + \frac{R_3}{R_4}\right)$$

Where  $V_{\text{FB}}$  is 0.5V reference voltage.

### **Input Inductor Selection**

A 1µH~3.3µH input inductor is recommended for most AIC3417 applications. Although small size and high efficiency are major concerns, the inductor should have low core losses at operation frequency and low DCR (copper wire resistance). It is important to ensure the inductor saturation current exceeding the peak inductor current in application to prevent core saturation. For CCM (Continuous Conduction Mode) operation, the peak inductor current can be calculated from:

$$\begin{split} I_{\text{PEAK}} = & I_{\text{IN}(\text{MAX})} + \frac{V_{\text{IN}(\text{MIN})} \cdot D_{(\text{MAX})}}{2 \times f_{\text{S}} \cdot L} \\ = & \frac{I_{\text{OUT}(\text{MAX})} \cdot V_{\text{OUT}}}{\eta \cdot V_{\text{IN}(\text{MIN})}} + \frac{V_{\text{IN}(\text{MIN})} \cdot D_{(\text{MAX})}}{2 \times f_{\text{S}} \cdot L} \end{split}$$

### Input Capacitor Selection

Surfaces mount 10µF or greater, X5R or X7R, ceramic capacitor is suggested for the input capacitor. The input capacitor provides a low impedance loop for the edges of pulsed current drawn by the AIC3417. Low ESR/ESL X7R and X5R ceramic capacitors are ideal for this function. To minimize stray inductance, the capacitor should be placed as close as possible to the IC. This keeps the high frequency content of the input current



localized, minimizing EMI and input voltage ripple. Always examine the ceramic capacitor DC voltage coefficient characteristics to get the proper value.

### **Output Capacitor Selection**

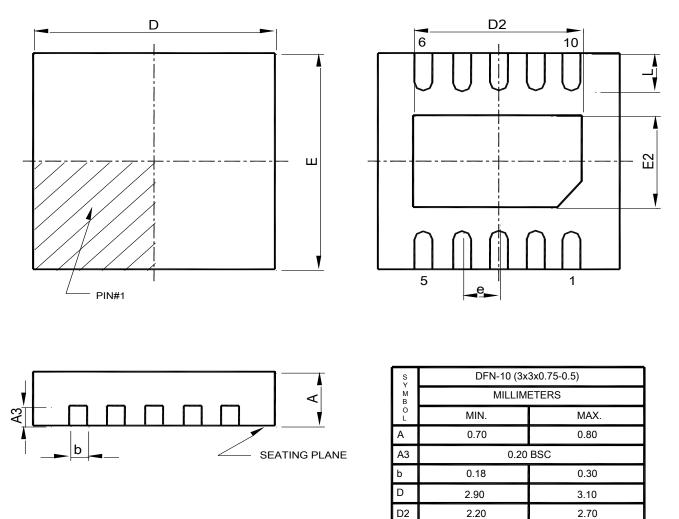
The output capacitor limits the output ripple and provides holdup during large load transitions. Two  $22\mu$ F, X5R or X7R, ceramic capacitors are suggested for the output capacitor. Typically the recommended capacitor range provides sufficient bulk capacitance to stabilize the output voltage during large load transitions and has the low ESR and ESL characteristics necessary for low output voltage ripple.

### **PCB Layout Guidance**

This is a considerably high frequency for DC-DC converters. PCB layout is important to guarantee satisfactory performance. It is recommended to make traces of the power loop, especially where the switching node is involved, as short and wide as possible. First of all, the inductor, input and output capacitor should be as close to the device as possible. Feedback and shutdown circuits should avoid the proximity of large AC signals involving the power inductor and switching node.



### • DFN -10 (3x3x0.75-0.5)



Е

E2

е

L

2.90

1.40

0.30

0.5 BSC

3.10

1.80

0.50

Note : 1. DIMENSION AND TOLERANCING CONFORM TO ASME Y14.5M-1994. 2.CONTROLLING DIMENSIONS : MILLIMETER , CONVERTED INCH DIMENSION ARE NOT NECESSARILY EXACT.

MAX

1 7 5

0.15

0.51

0 25

5.00

3.50

4.00

2.55

6.20

0.50

1.27

8°

1.27 BSC

5.80

0.25

0.40

0°

e

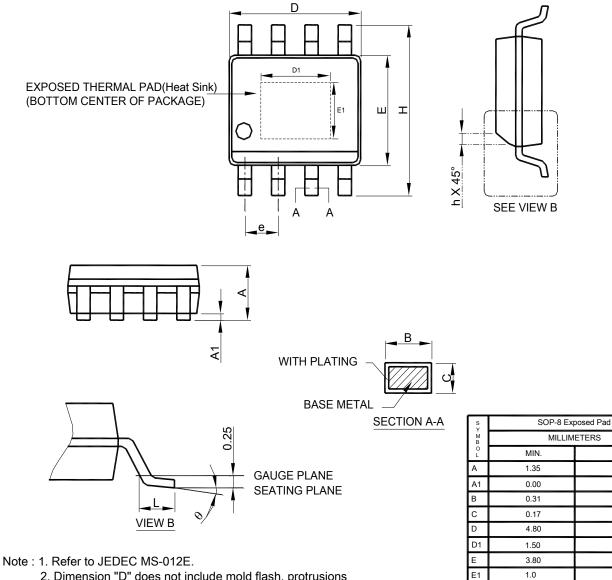
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## **PHYSICAL DIMENSION (Continued)**

### **SOP-8 Exposed Pad**

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- 2. Dimension "D" does not include mold flash, protrusions
  - or gate burrs. Mold flash, protrusion or gate burrs shall not exceed 6 mil per side .
  - 3. Dimension "E" does not include inter-lead flash or protrusions.
  - 4. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.

Note <sup>.</sup>	
11010.	

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